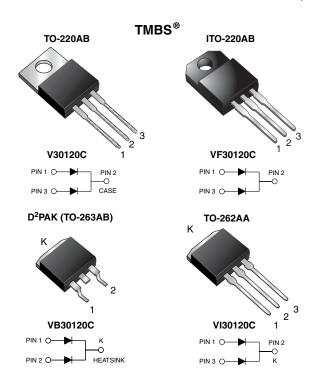
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Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V_{RRM}	120 V					
I _{FSM}	150 A					
V _F at I _F = 15 A	0.68 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

• High efficiency operation

(e3)

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)

 Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V30120C	VF30120C	VB30120C	VI30120C	UNIT	
Max. repetitive peak reverse voltage		V_{RRM}	120				V	
Max. average forward rectified current	per device	1	30					
(fig. 1)	per diode	I _{F(AV)}	15					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150			Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode		E _{AS}	130			mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	0.5		Α			
Voltage rate of change (rated V _R)		dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500			V		
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150				°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	$I_R = 1.0 \text{ mA}$	T _A = 25 °C	V_{BR}	120 (min.)	-	V		
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C	V _F	0.56	-	V		
	I _F = 7.5 A			0.71	-			
	I _F = 15 A			0.86	0.97			
	I _F = 5 A	T _A = 125 °C		0.50	-			
	I _F = 7.5 A			0.60	-			
	I _F = 15 A			0.68	0.76			
Reverse current per diode (2)	V _R = 90 V	T _A = 25 °C	I _R	11	-	μΑ		
		T _A = 125 °C		8	-	mA		
	V _D = 120 V -	T _A = 25 °C		-	800	μΑ		
		T _A = 125 °C		17	50	mA		

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30120C	VF30120C	VB30120C	VI30120C	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.2	4.5	2.2	2.2	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30120C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VF30120C-E3/4W	1.75	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB30120C-E3/4W	1.38	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB30120C-E3/8W	1.38	8W	800/reel	Tape and reel			
TO-262AA	VI30120C-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

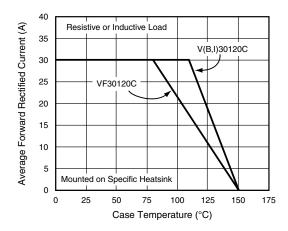


Fig. 1 - Maximum Forward Current Derating Curve

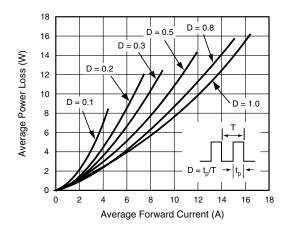


Fig. 2 - Forward Power Loss Characteristics Per Diode

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

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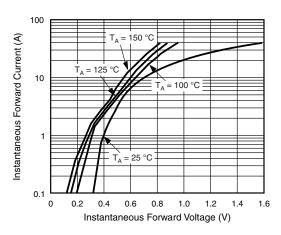


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

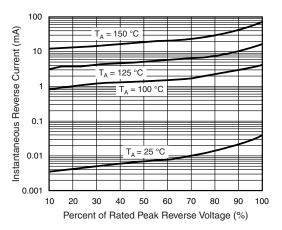


Fig. 4 - Typical Reverse Characteristics Per Diode

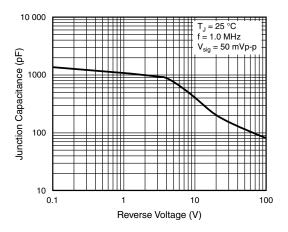


Fig. 5 - Typical Junction Capacitance Per Diode

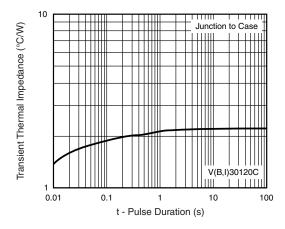


Fig. 6 - Typical Transient Thermal Impedance Per Diode

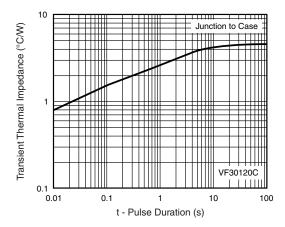
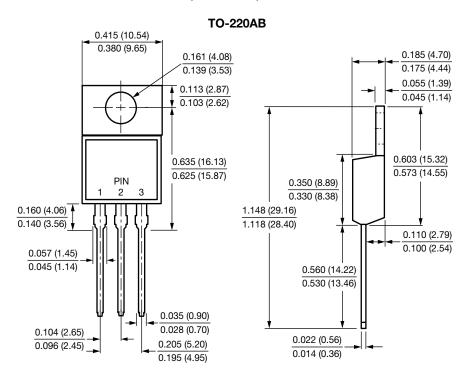


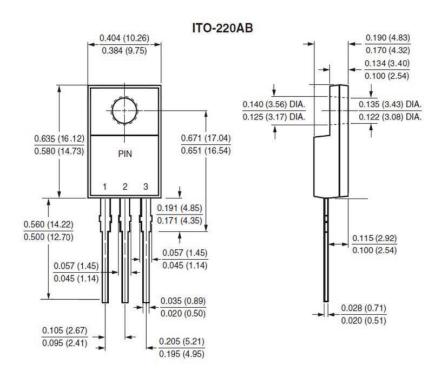
Fig. 7 - Typical Transient Thermal Impedance Per Diode

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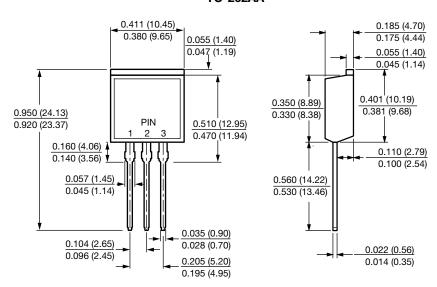
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



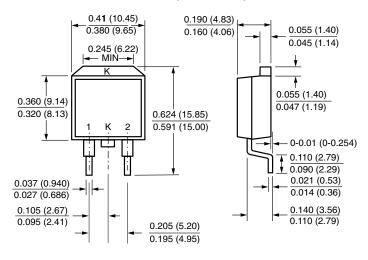


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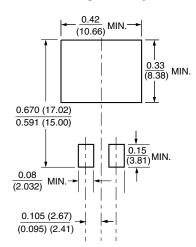
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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